

FCPF260N60E_F152

N-Channel SuperFET® II MOSFET

600 V, 15 A, 260 mΩ

Features

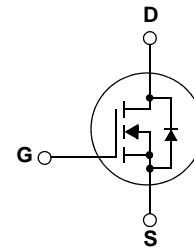
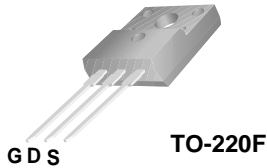
- 650 V @ T_J = 150°C
- Max. R_{DS(on)} = 260 mΩ
- Ultra Low Gate Charge (Typ. Q_g = 48 nC)
- Low Effective Output Capacitance (Typ. C_{oss,eff} = 129 pF)
- 100% Avalanche Tested

Applications

- LCD / LED / PDP TV Lighting
- Solar Inverter
- AC-DC Power Supply

Description

SuperFET® II MOSFET is Fairchild Semiconductor®'s first generation of high voltage super-junction (SJ) MOSFET family that is utilizing charge balance technology for outstanding low on-resistance and lower gate charge performance. This advanced technology is tailored to minimize conduction loss, provide superior switching performance, and withstand extreme dv/dt rate and higher avalanche energy. Consequently, SuperFET® II MOSFET is suitable for various AC/DC power conversion for system miniaturization and higher efficiency.



MOSFET Maximum Ratings T_C = 25°C unless otherwise noted


Symbol	Parameter	FCPF260N60E_F152	Unit
V _{DSS}	Drain to Source Voltage	600	V
V _{GSS}	Gate to Source Voltage	- DC	±20
		- AC (f > 1Hz)	±30
I _D	Drain Current	-Continuous (T _C = 25°C)	15*
		-Continuous (T _C = 100°C)	9.5*
I _{DM}	Drain Current	- Pulsed (Note 1)	45*
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	292.5
I _{AR}	Avalanche Current	(Note 1)	3.0
E _{AR}	Repetitive Avalanche Energy	(Note 1)	1.56
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	20
	MOSFET dv/dt		100
P _D	Power Dissipation	(T _C = 25°C)	36
		- Derate above 25°C	0.29
T _J , T _{STG}	Operating and Storage Temperature Range	-55 to +150	°C
T _L	Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds	300	°C

*Drain current limited by maximum junction temperature

Thermal Characteristics

Symbol	Parameter	FCPF260N60E_F152	Unit
R _{θJC}	Thermal Resistance, Junction to Case	3.5	°C/W
R _{θCS}	Thermal Resistance, Case to Heat Sink (Typical)	0.5	
R _{θJA}	Thermal Resistance, Junction to Ambient	62.5	

Package Marking and Ordering Information

Device Marking	Device	Package	Eco Status	Packaging Type	Quantity
FCPF260N60E	FCPF260N60E_F152	TO-220F	Green 	Tube	50

For Fairchild's definition of "green" Eco Status, please visit: http://www.fairchildsemi.com/company/green/rohs_green.html.

Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
--------	-----------	-----------------	------	------	------	------

Off Characteristics

BV_{DSS}	Drain to Source Breakdown Voltage	$V_{GS} = 0V, I_D = 10mA, T_J = 25^\circ\text{C}$	600	-	-	V
		$V_{GS} = 0V, I_D = 10mA, T_J = 150^\circ\text{C}$	650	-	-	V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 10mA$, Referenced to 25°C	-	0.67	-	$V/^\circ\text{C}$
BV_{DS}	Drain-Source Avalanche Breakdown Voltage	$V_{GS} = 0V, I_D = 15A$	-	700	-	V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 480V, V_{GS} = 0V$	-	-	10	μA
		$V_{DS} = 480V, T_C = 125^\circ\text{C}$	-	-	10	
I_{GSS}	Gate to Body Leakage Current	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	± 100	nA

On Characteristics

$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250\mu\text{A}$	2.5	-	3.5	V
$R_{DS(on)}$	Static Drain to Source On Resistance	$V_{GS} = 10V, I_D = 7.5A$	-	0.22	0.26	Ω
g_{FS}	Forward Transconductance	$V_{DS} = 20V, I_D = 7.5A$	-	15.5	-	S

Dynamic Characteristics

C_{iss}	Input Capacitance	$V_{DS} = 25V, V_{GS} = 0V$ $f = 1\text{MHz}$	-	1880	2500	pF
C_{oss}	Output Capacitance		-	1330	1770	pF
C_{rfs}	Reverse Transfer Capacitance		-	85	130	pF
C_{oss}	Output Capacitance	$V_{DS} = 380V, V_{GS} = 0V, f = 1\text{MHz}$	-	32	-	pF
$C_{oss \text{ eff.}}$	Effective Output Capacitance	$V_{DS} = 0V \text{ to } 480V, V_{GS} = 0V$	-	129	-	pF
$Q_{g(tot)}$	Total Gate Charge at 10V	$V_{DS} = 380V, I_D = 7.5A$ $V_{GS} = 10V$	-	48	62	nC
Q_{gs}	Gate to Source Gate Charge		-	7.4	-	nC
Q_{gd}	Gate to Drain "Miller" Charge		(Note 4)	-	17	-
ESR	Equivalent Series Resistance	$f = 1\text{MHz}$	-	5.8	-	Ω

Switching Characteristics

$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = 380V, I_D = 7.5A$ $V_{GS} = 10V, R_G = 4.7\Omega$	-	20	50	ns
t_r	Turn-On Rise Time		-	11	32	ns
$t_{d(off)}$	Turn-Off Delay Time		-	89	188	ns
t_f	Turn-Off Fall Time		(Note 4)	-	13	36

Drain-Source Diode Characteristics

I_S	Maximum Continuous Drain to Source Diode Forward Current	-	-	15	A	
I_{SM}	Maximum Pulsed Drain to Source Diode Forward Current	-	-	45	A	
V_{SD}	Drain to Source Diode Forward Voltage	$V_{GS} = 0V, I_{SD} = 7.5A$	-	-	1.2	V
t_{rr}	Reverse Recovery Time	$V_{GS} = 0V, I_{SD} = 7.5A$ $di_F/dt = 100A/\mu\text{s}$	-	270	-	ns
Q_{rr}	Reverse Recovery Charge		-	3.6	-	μC

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature
2. $I_{AS} = 3A, V_{DD} = 50V, R_G = 25\Omega$, Starting $T_J = 25^\circ\text{C}$
3. $I_{SD} \leq 7.5A, di/dt \leq 200A/\mu\text{s}, V_{DD} \leq BV_{DSS}$, Starting $T_J = 25^\circ\text{C}$
4. Essentially Independent of Operating Temperature Typical Characteristics

Typical Performance Characteristics

Figure 1. On-Region Characteristics

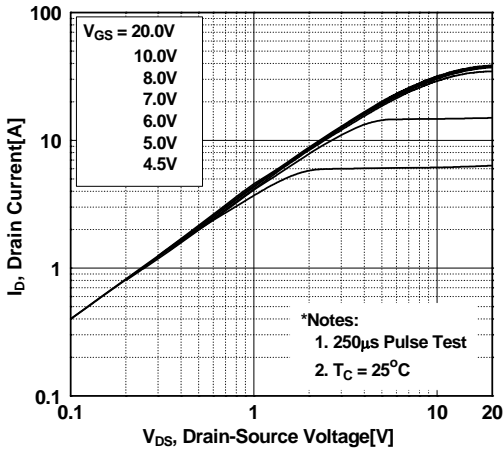


Figure 2. Transfer Characteristics

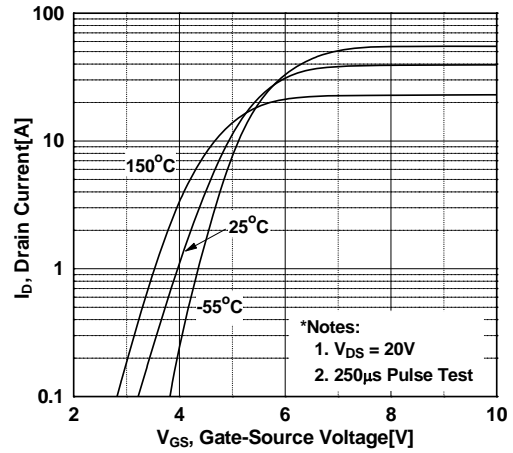


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

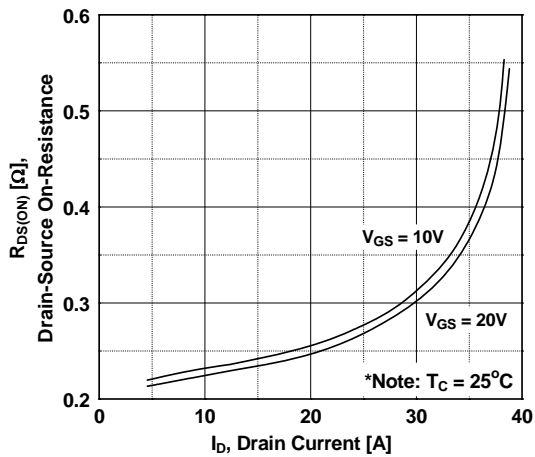


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

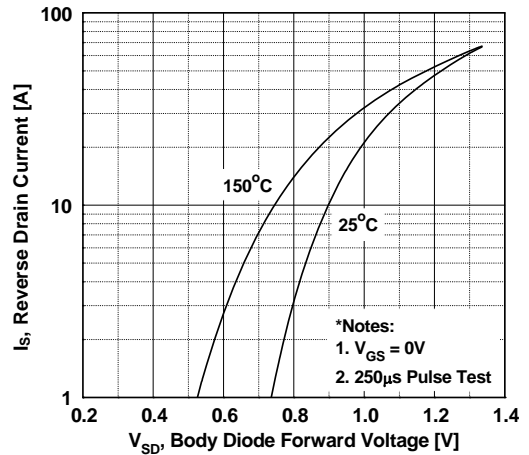


Figure 5. Capacitance Characteristics

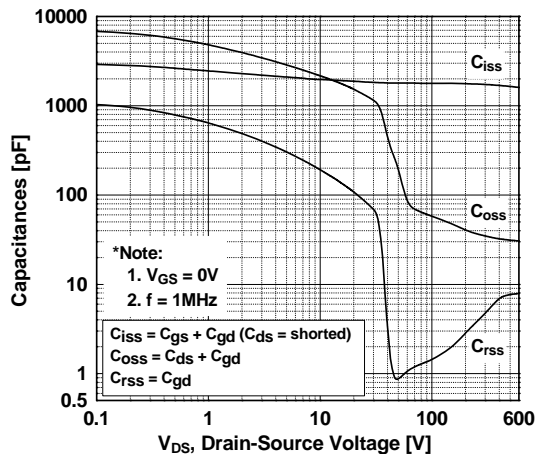
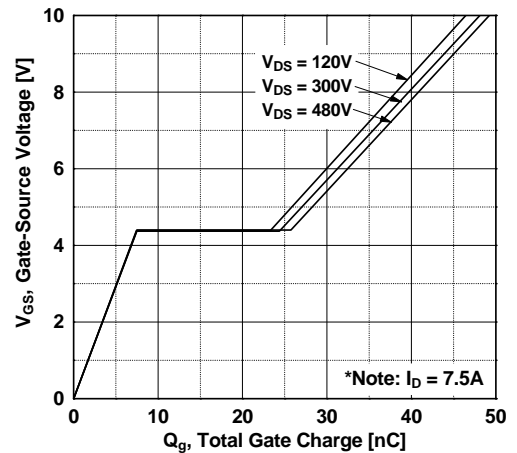


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

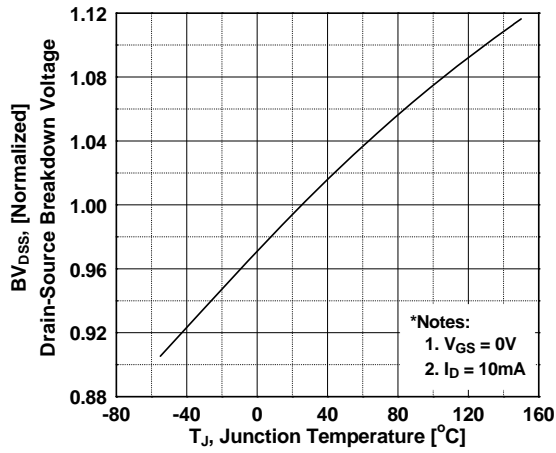


Figure 8. On-Resistance Variation vs. Temperature

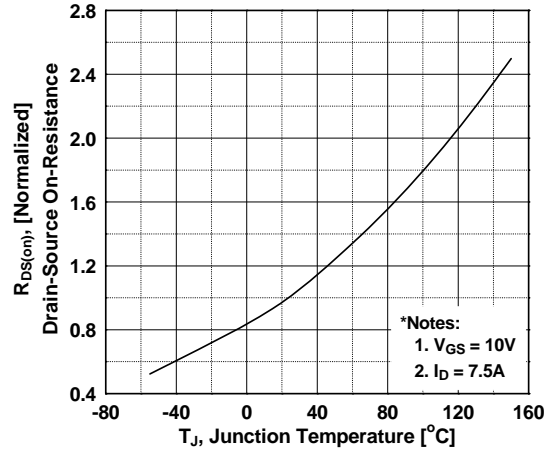


Figure 9. Maximum Safe Operating Area vs. Case Temperature

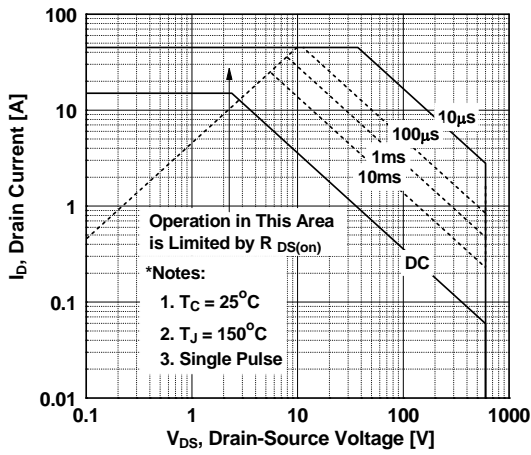


Figure 10. E_{oss} vs. Drain to Source Voltage Switching Capability

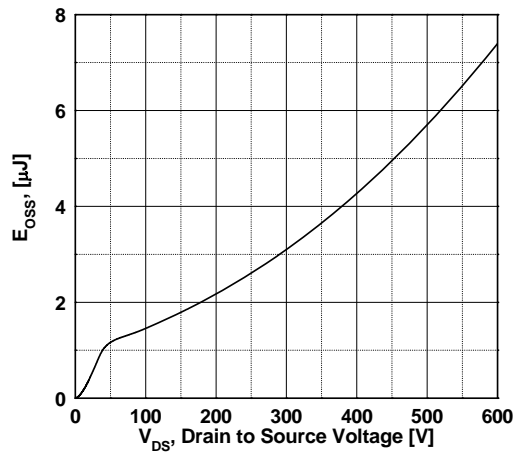
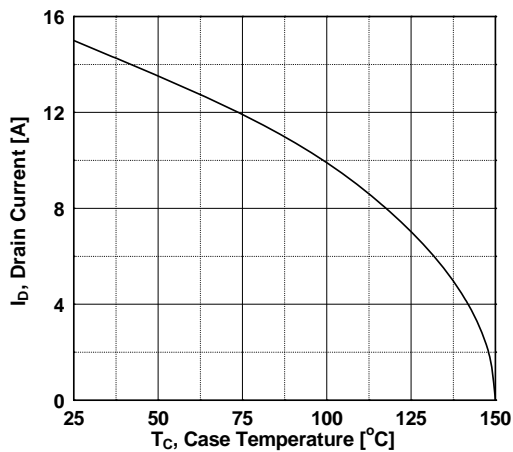
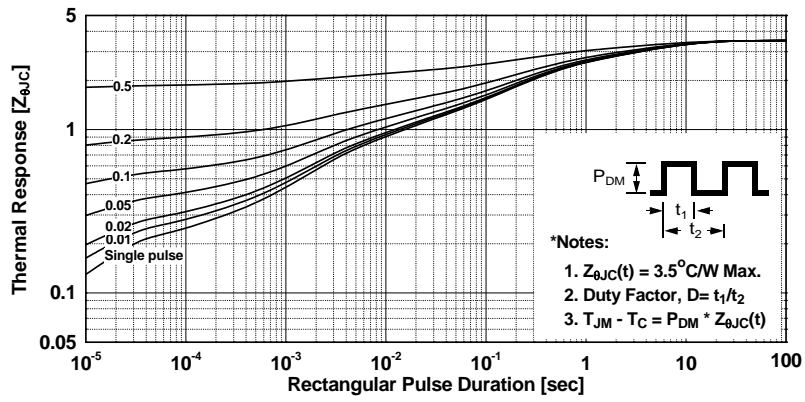


Figure 11. Maximum Drain Current

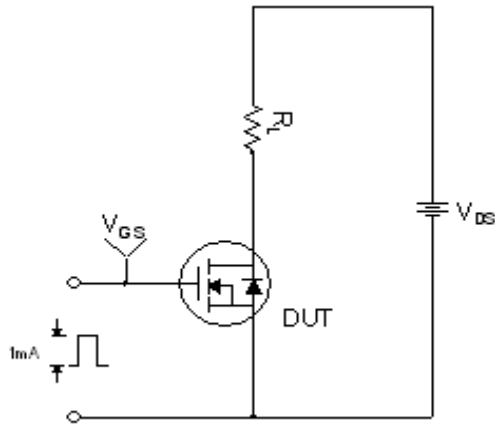


Typical Performance Characteristics (Continued)

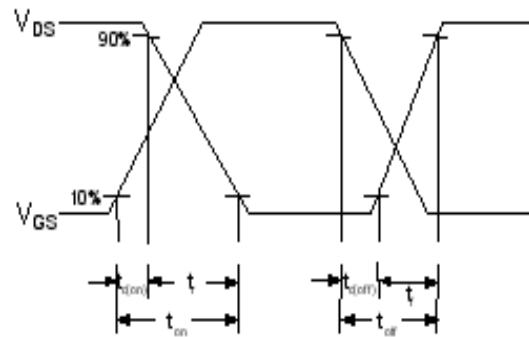
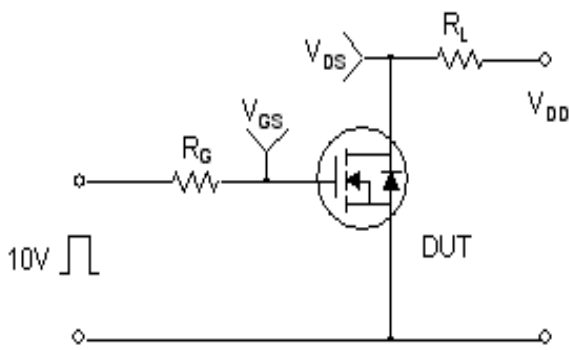
Figure 12. Transient Thermal Response Curve



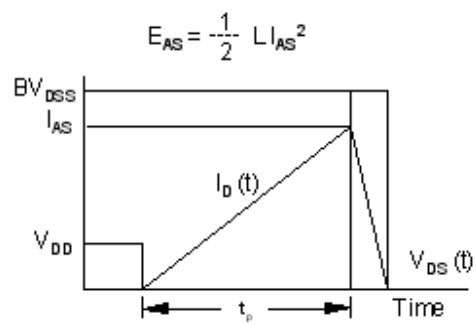
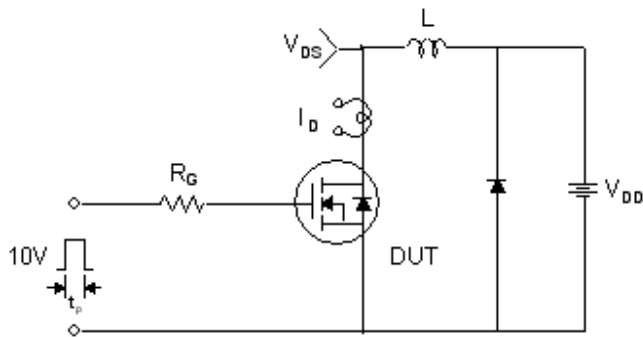
Gate Charge Test Circuit & Waveform



Resistive Switching Test Circuit & Waveforms



Unclamped Inductive Switching Test Circuit & Waveforms

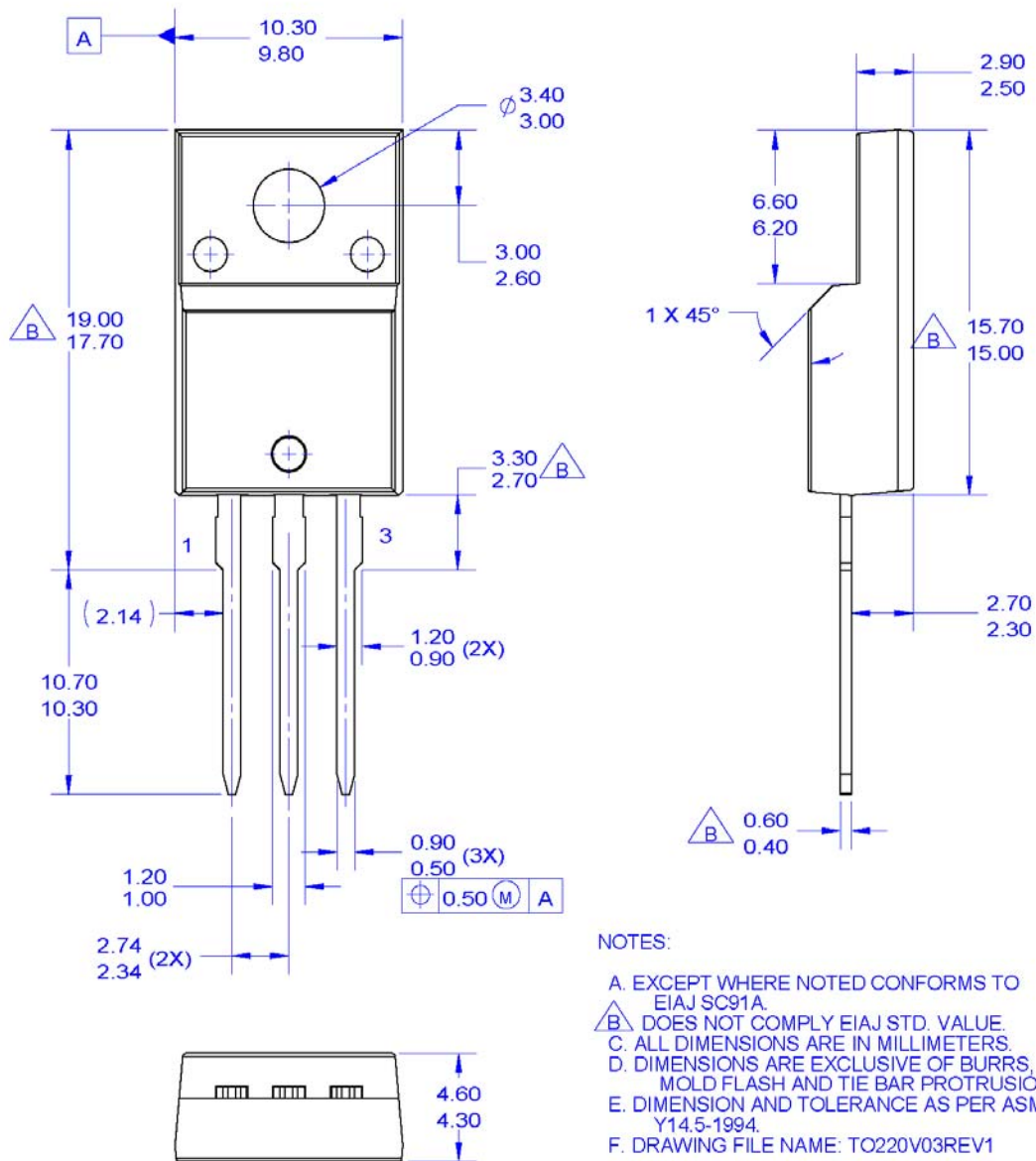


Peak Diode Recovery dv/dt Test Circuit & Waveforms



Mechanical Dimensions

TO-220F



*** Front/Back Side Isolation Voltage : AC 2500V**

TO-220, MOLDED, 3LD, FULL PACK, EIAJ SC91

Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a Fairchild Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products.


Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings:

http://www.fairchildsemi.com/package/packageDetails.html?id=PN_TF220-0A3



TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

- | | | | |
|---|---|----------------------------|------------------|
| 2Cool™ | FPST™ | PowerTrench® | Sync-Lock™ |
| AccuPower™ | F-PFST™ | PowerXST™ | SYSTEM GENERAL® |
| AX-CAP®* | FRFET® | Programmable Active Droop™ | TinyBoost™ |
| BitSiC™ | Global Power Resource SM | QFET® | TinyBuck™ |
| Build it Now™ | Green Bridge™ | QST™ | TinyCalc™ |
| CorePLUS™ | Green FPS™ | Quiet Series™ | TinyLogic® |
| CorePOWER™ | Green FPS™ e-Series™ | RapidConfigure™ | TINYOPTO™ |
| CROSSVOLT™ | Gmax™ | GTO™ | TinyPower™ |
| CTL™ | IntelliMAX™ | ISOPLANAR™ | TinyPVM™ |
| Current Transfer Logic™ | Marking Small Speakers Sound Louder and Better™ | MegaBuck™ | TinyWire™ |
| DEUXPEED® | MICROCOUPLER™ | MicroFET™ | TranSiC® |
| Dual Cool™ | MicroPak™ | MicroPak2™ | TriFault Detect™ |
| EcoSPARK® | MillerDrive™ | MotionMax™ | TRUECURRENT®* |
| EfficientMax™ | mWSaver™ | OptoHiT™ | µSerDes™ |
| ESBC™ | OPTOLOGIC® | OPTOPLANAR® | UHC® |
|  | | | Ultra FRFET™ |
| Fairchild® | | | UniFET™ |
| Fairchild Semiconductor® | | | VCX™ |
| FACT Quiet Series™ | | | VisualMax™ |
| FACT® | | | VoltagePlus™ |
| FAST® | | | XS™ |
| FastvCore™ | | | |
| FETBench™ | | | |

*Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used here in:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Sales Support. Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS
Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

Rev. I64

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.

